The RF Line

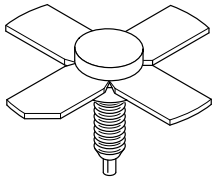
NPN Silicon RF Power Transistors

MRF652
MRF652S

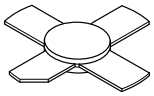
5.0 W, 512 MHz RF POWER TRANSISTORS NPN SILICON

Designed for 12.5 Vdc UHF large–signal, amplifier applications in industrial and commercial FM equipment operating to 512 MHz.

- Guaranteed 12.5 Volt, 512 MHz Characteristics
  Output Power = 5.0 Watts
  Minimum Gain = 10 dB
  Efficiency = 65% (Typ)
- Typical Performance at 512 MHz, 12.5 V, 5.0 W Output = 6.0 dB
- Series Equivalent Large–Signal Characterization
- Gold Metallized, Emitter Ballasted for Long Life and Reliability
- Capable of 30:1 VSWR Load Mismatch at 15.5 V Supply Voltage
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.



CASE 244–04, STYLE 1
MRF652



CASE 249–06, STYLE 1
MRF652S

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	16	Vdc
Collector–Base Voltage	V_{CBO}	36	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous	I_C	2.0	Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	25 143	Watts mW/°C
Storage Temperature Range	T_{stg}	–65 to +150	°C
Operating Junction Temperature	T_J	200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	7.0	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

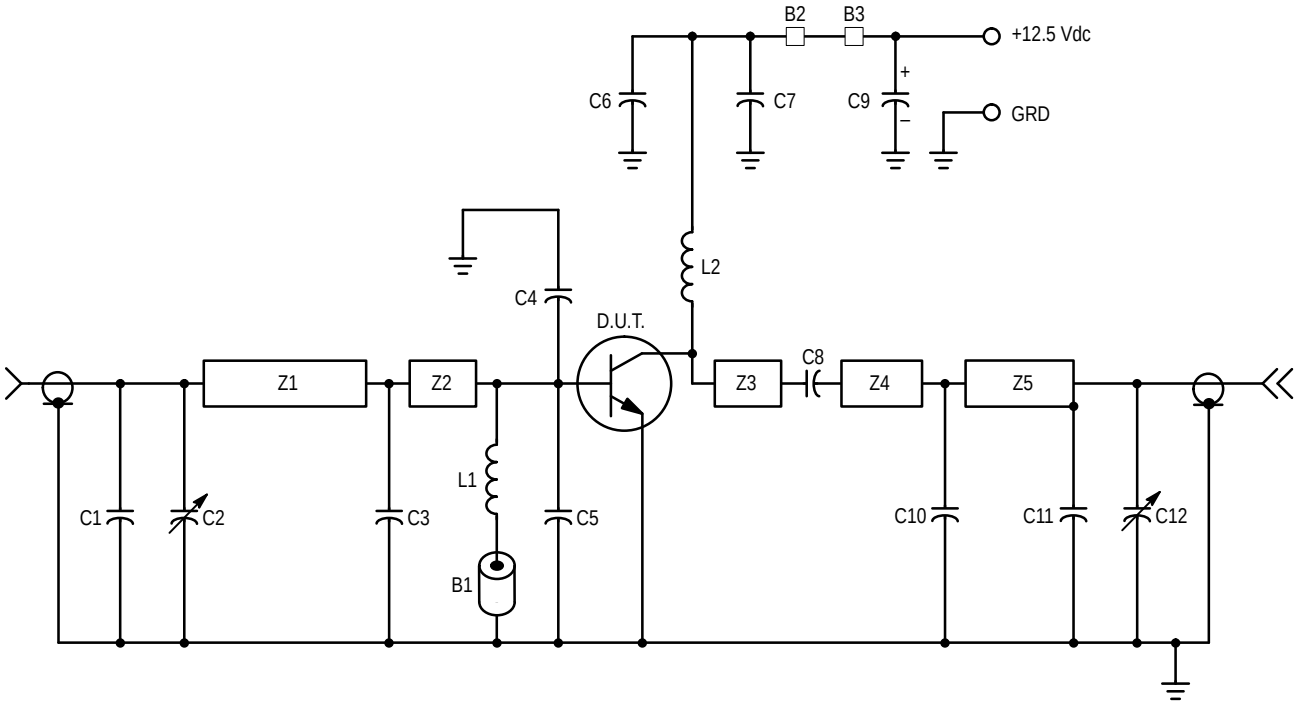
Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I_C = 25 mAdc, I_B = 0)	$V_{(BR)CEO}$	16	—	—	Vdc
Collector–Emitter Breakdown Voltage (I_C = 25 mAdc, V_{BE} = 0)	$V_{(BR)CES}$	36	—	—	Vdc
Collector–Base Breakdown Voltage (I_C = 25 mAdc, I_E = 0)	$V_{(BR)CBO}$	36	—	—	Vdc
Emitter–Base Breakdown Voltage (I_E = 5.0 mAdc, I_C = 0)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector Cutoff Current (V_{CE} = 15 Vdc, V_{BE} = 0)	I_{CES}	—	—	1.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I_C = 200 mAdc, V_{CE} = 5.0 Vdc)	h_{FE}	10	—	150	—

(continued)

© Motorola, Inc. 1995

ELECTRICAL CHARACTERISTICS — continued (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
DYNAMIC CHARACTERISTICS						
Output Capacitance (V_{CB} = 15 Vdc, I_E = 0, f = 1.0 MHz)		C_{ob}	—	9.5	15	pF
FUNCTIONAL TESTS						
Common–Emitter Amplifier Power Gain (V_{CC} = 12.5 Vdc, P_{out} = 5.0 W)	f = 512 MHz f = 870 MHz	G_{pe}	10 —	11 6.0	— —	dB
Collector Efficiency (V_{CC} = 12.5 Vdc, P_{out} = 5.0 W, f = 512 MHz)		η	60	65	—	%
Load Mismatch (V_{CC} = 15.5 Vdc, P_{in} = 500 mW, f = 512 MHz, VSWR = 30:1, At All Phase Angles)		ψ	No Degradation in Output Power			



B1, B2, B3 — Ferrite Bead
C1 — 7.0 pF Unelco Mica
C2 — 1.0–6.0 pF Johanson Variable 5201
C3 — 15 pF Unelco Mica
C4 — 43 pF Mini–Underwood Mica
C5 — 56 pF Mini–Underwood Mica
C6 — 1000 pF Unelco Mica
C7 — 0.1 μF Ceramic
C8 — 68 pF Mini–Underwood Mica
C9 — 1.0 μF Electrolytic 25 V
C10, C11 — 5.0 pF Unelco Mica
C12 — 1.0–10 pF Johanson Variable 5501
L1, L2 — 6 Turns, 20 AWG Wire 0.125″ ID
Z1, Z2 — 25 Ohm μStripline
Z3, Z4, Z5 — 50 Ohm μStripline
Board — 0.032″ Glass–Teflon

Figure 1. 440–512 MHz Broadband Test Circuit

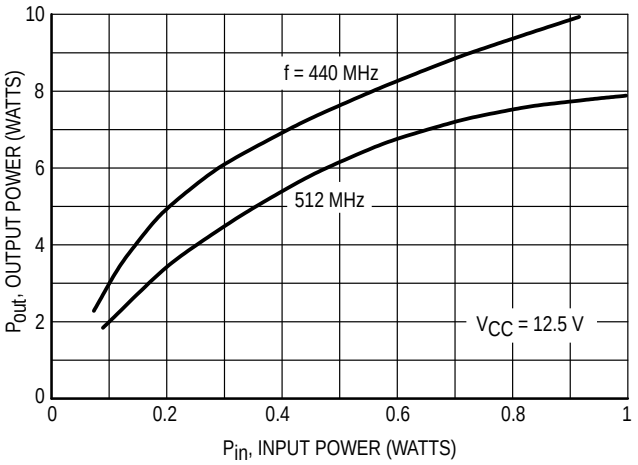


Figure 2. Output Power versus Input Power

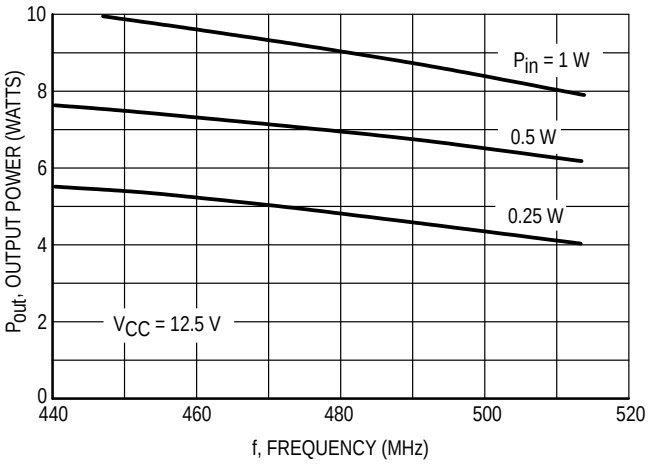


Figure 3. Output Power versus Frequency

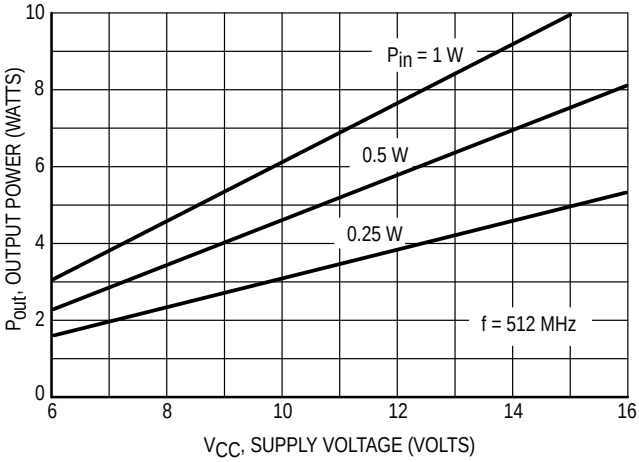


Figure 4. Output Power versus Supply Voltage

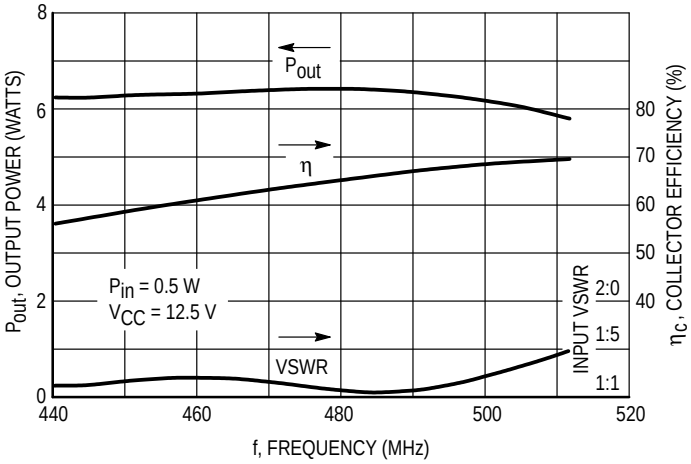
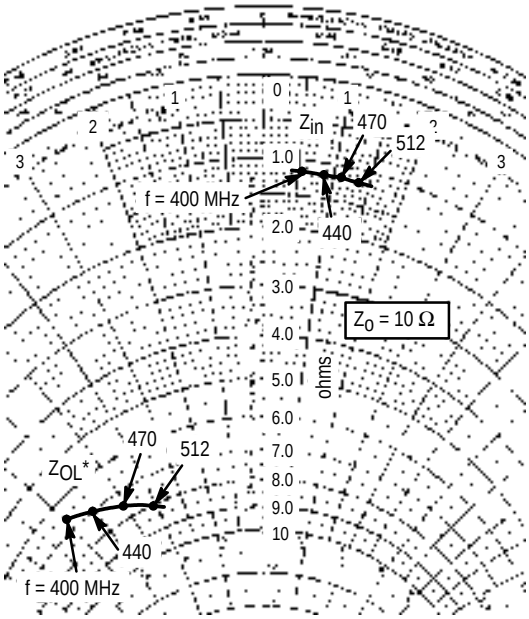


Figure 5. Typical Broadband Circuit Performance



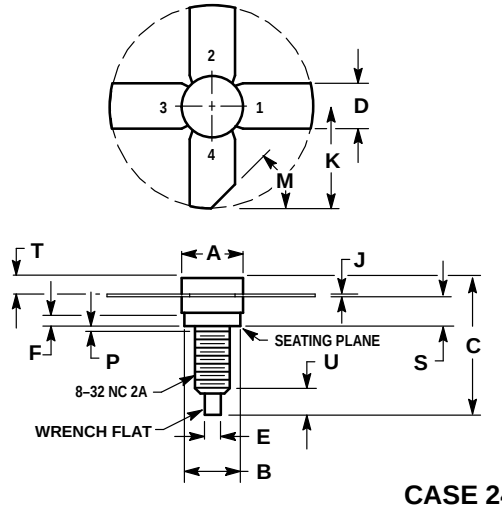
V_{CC} = 12.5 Vdc
P_{out} = 5.0 W

f MHz	Z_{in} Ohms	Z_{OL}* Ohms
400	1.18 + j0.54	6.7 – j6.9
440	1.19 + j0.88	7.05 – j6.1
470	1.19 + j1.11	7.6 – j5.1
512	1.19 + j1.35	8.1 – j4.1

Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 6. Series Equivalent Input/Output Impedance

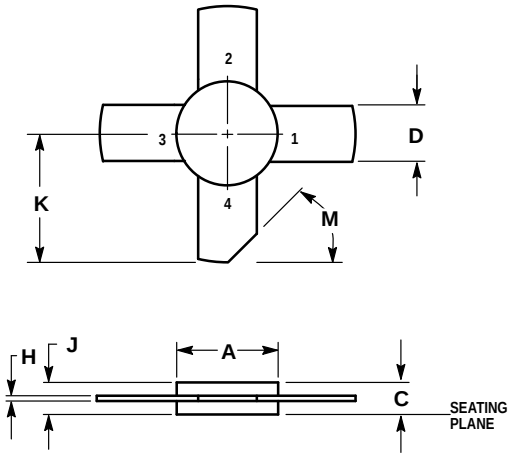
PACKAGE DIMENSIONS



DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	7.06	7.26	0.278	0.286
B	6.20	6.50	0.244	0.256
C	14.99	16.51	0.590	0.650
D	5.46	5.96	0.215	0.235
E	1.40	1.65	0.055	0.065
G	1.52	—	0.060	—
J	0.08	0.17	0.003	0.007
K	11.05	—	0.435	—
M	45° NOM		45° NOM	
P	—	1.27	—	0.050
S	3.00	3.25	0.118	0.128
T	1.40	1.77	0.055	0.070
U	2.92	3.68	0.115	0.145

STYLE 1:
PIN 1. EMITTER
2. BASE
3. EMITTER
4. COLLECTOR

CASE 244–04
ISSUE J
MRF652



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. SEATING PLANE = GROUND AND IS CONNECTED TO PIN 1 AND 3.

DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	0.271	0.286	6.88	7.26
C	0.112	0.136	2.84	3.45
D	0.215	0.235	5.46	5.97
H	0.055	0.065	1.40	1.65
J	0.003	0.007	0.08	0.18
K	0.435	—	11.05	—
M	45° REF		45° REF	

STYLE 1:
PIN 1. EMITTER
2. BASE
3. EMITTER
4. COLLECTOR

CASE 249–06
ISSUE H
MRF652S

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. “Typical” parameters can and do vary in different applications. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and M are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:
USA / EUROPE: Motorola Literature Distribution;
P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609
INTERNET: http://Design–NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, Toshikatsu Otsuki,
6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–3521–8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298